Nanostructured Anti-Reflective (AR) surfaces have attracted a focused attention during the last few years and offer an alternative to AR coatings. Recent nanopatterning approaches have allowed fabrication of bioinspired nanostructured surfaces with unprecedented broadband and omnidirectional AR properties. However, nanofabrication methods face major challenges for reaching industrial maturity including high capital expenditure cost, scalability, reliability and adaptability of the technologies. Block copolymer (BCP) films provide one way to overcome some of these limitations by offering scalable and versatile masks to fabricate well-defined, uniform and tunable nanostructures on a variety of substrates at a modest price. This article aims at highlighting recent efforts for assembling such AR nanostructured surfaces with BCP films and the challenges yet to tackle prior to commercialization.

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Manuscript submitted January 7, 2019; revised manuscript received July 17, 2019. Published September 20, 2019. This paper is part of the JES Focus Issue on Sensor Reviews.

Reflection of light is one of the critical issues limiting the efficiency of devices in several application fields, including optics, photovoltaics and detectors.1,2 As early as 1879, the issue of reflectivity of optical substrates was a well studied. Lord Rayleigh proposed that reflection of light could be reduced by smoothing the refractive index transition between the substrate and its environment.3 Following this concept, basic antireflective (AR) coatings were developed (Figure 1a), and later refined to utilize destructive interference of reflected light caused by multilayer dielectric coatings, alternating high and low refractive indexes.4–6 However, modern optoelectronic devices place new demands on the optics market that cannot be addressed at a reasonable cost by such multilayer dielectric coatings. Indeed, current optoelectronic devices require (1) broadband AR over large areas; (2) insensitivity to the incident angle (omnidirectional); and (3) chemical and mechanical robustness for end-use application.

Such properties are often found in the natural world.7 For instance, a close inspection of the cornea of night-flying moths reveals an ordered array of conical protuberances, typically of 200 nm height and spacing.8 Biomimicry of these surface nanostructures became a major research avenue in the pursuit of AR, by graded refractive index. (Figure 1b). As early as 1973, moth-eye coatings applied to glass gave a reduction of the reflection of “white light” (a broad spectrum of visible light) from 5.5% to 0.2%.9 These promising results triggered a surge in development of similar AR coatings including, but not restricted to, oblique incidence thin film deposition methods,10 replicated polymer structures,11–13 nanoporous polymers14,15 and carbon nanotube arrays.16,17

In recent years, improvement of micro/nanofabrication tools and methods have enabled the nanostructuring of substrate surfaces directly, creating robust AR surfaces without coatings (Figures 1c, 1d).18–22 This article aims to highlight recent efforts for fabrication of such AR nanostructured surfaces and the challenges remaining that should be addressed prior to commercialization.

Current Status

Overview.—Direct nanostructuring of the substrate surface offers several advantages over coatings in the fields of optics, eliminating intermediate layers between the substrate and its environment reduces the risk of releasing hazardous materials, and enables better control over the substrate/environment interaction. Several strategies have thus been developed to fabricate a nanostructure on the surface of silicon, fused silica, sapphire and PDMS. These include direct laser writing,23 direct reactive ion etching,24 chemical etching,25 electrochemical oxidation and imprinting.26,27 However, the lack of scalability, adaptability to different substrate materials and geometries (e.g. curvature) and high capital/operating cost of such fabrication methods are a major technological hurdle for exploitation. Some of these challenges can be overcome by using lithographic approaches, introducing a process step of masking the substrates with a nanoscale pattern, to be transferred to the surface. Therefore, the preparation

Figure 1. Schematic depiction of (a) interaction of light through one layer toward substrate, (b) light interaction with a nanopatterned coating and (c) light interaction with a nanopatterned substrate. (d) Illustration of refractive index change with respect to (c).25 Adapted with permission from Ref. 23, Copyright 2015, Royal Society of Chemistry.

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Table I. Reported methods for fabricating AR surfaces using a mask.

<table>
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<tr>
<th>Ref</th>
<th>Mask type and etching approach</th>
<th>Substrate(s) and structure dimensions demonstrated</th>
<th>Advantages/drawbacks</th>
</tr>
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<tr>
<td>2,34–37</td>
<td>Mask: Metal microdomains either sputtered or thermally dewetted</td>
<td>Substrates: Glass, germanium, sapphire and teflon Nanopillars and nanocones up to 192 nm diameter and 350 nm height</td>
<td>Size-tunable and excellent contrast etch. Poor size distribution of the nanostructures. Special equipment required.</td>
</tr>
<tr>
<td>40</td>
<td>Mask: Colloidal monolayer + metal evaporation Etch: Metal assisted chemical etching</td>
<td>Substrate: Silicon Nanowires up to 475 nm diameter and 12 μm height</td>
<td>Simple and scalable. Excellent aspect ratio on silicon. Density of nanostructures limited. Special equipment required. Low cost, scalable, tunable nanostructures, high aspect ratio, adaptable on objects with complex shape (solution based)</td>
</tr>
<tr>
<td>41–44,</td>
<td>Mask: Self-assembled block-copolymer film Etch: ICP or plasma etching</td>
<td>Substrates: Silicon, glass, GaN Nanopillars up to 110 nm diameter and 1150 nm height</td>
<td>Etch contrast limited Fast, easy to fine-tune size and morphology, high aspect ratio structures Special equipment required</td>
</tr>
<tr>
<td>45</td>
<td>Laser direct writing and laser interference lithography</td>
<td>Silicon oxide</td>
<td></td>
</tr>
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of such masks could be considered as a critical factor for preparing high-performance AR surfaces and we anticipate its successful industrial applications. These masks should ideally achieve, at reasonable cost and with scalable processes: (i) uniformity and versatility of the pattern, (ii) tolerance to the substrate size and geometry (iii) a high contrast pattern transfer (etch) for a range of substrates. Accordingly, several lithographic approaches can be considered viable for fabricating nanostructures on a wide variety of materials including silicon, glass, sapphire and GaN30–33 (Table I).

Block-copolymer masks for AR surfaces.—Block-copolymer (BCP) films deposited by solution-processing techniques41 can self-assemble into microphase-separated arrays, providing well-defined periodic nanostructured surfaces over large areas and with a remarkable compatibility with both the substrate material and geometry.46,47 The characteristics of each block composing the BCP, including their Flory-Huggins interaction parameter (χ), their degree of polymerization (N), and their volume fraction (fA), enable a range of microphase separation regimes that can be observed both theoretically and experimentally.48 Segregation of the different blocks composing the BCP into well-controlled microdomains may be influenced via a few parameters including the BCP-substrate interaction, the film thickness, the temperature and the solvent (Figure 2a).49 In practice, different strategies are used to induce and control the microphase separation and self-assembly, including thermal annealing,50 solvent vapor annealing (SVA),51 solvothermal annealing,52 microwave-assisted SVA,53–55 chemical substrate modification and patterning,56 graphoepitaxy,57 electrical/magnetic field alignment,58 and shear alignment.59 While each technique has merits and demerits,60–62 the wide variety of strategies contributes to the versatility of the BCP pattern as a mask. Depending on the substrate to be etched, microphase separated BCP films can be further treated to generate either polymer or metal-oxide masks with the desirable etch contrast property (Figure 2b routes 1 and 2).

Paivanranta et al.42 have used BCPs to create antireflective nanostructures on fused silica, and were able to reduce the reflectivity of fused silica to below 1%. Thermal annealing of a film of lamellar polystyrene-block-poly(methyl methacrylate) (PS-b-PMMA, PS:PMMA ~1:1), on a chromium coated fused silica formed PMMA microdomains oriented perpendicular to the substrate. Selective removal of the PMMA block yielded a PS pattern, which was used as an intermediate mask to etch the Cr layer, creating the final etch mask to dry etch the fused silica.

Using the same BCP but a different volume fraction (PS:PMMA ~7:3), Rahman et al.33 obtained 25-nm-diameter PMMA cylindrical microdomains within a PS matrix, hexagonally arranged with a separation of 40 nm to 67 nm depending on the BCP molecular weight. Impregnation of PMMA domains with alumina using sequential in-
filtration synthesis, followed by oxygen plasma removal of the BCP yielded an aluminum oxide mask that was used to dry etch the silicon substrate. This process resulted in silicon nanopillars, with a varying aspect ratio that could be tuned by changing the etching time (Figure 3a). The obtained nanostructured surface mimics the moth eye structure, reducing surface reflectance from 35% (flat surface) to <1% in the visible range and at incident angles below 60 degrees. The nanostructured silicon, used in a solar cell, significantly enhanced the cell performance. However, at higher angles of incidence, the reflection increased dramatically, to about 40%. This is mainly attributed to relatively small periodicity of the nanostructure obtained from the block copolymer mask, in comparison to the wavelength of the visible light, and the height of the nanopillars. Synthesizing high molecular weight block copolymers (to enable masks with higher periodicity), that still have reliable phase separation, is the main fundamental challenge for wider application of this technique.

Recently, Mokarian et al.42 “trapped” a non-equilibrium structure in ultra-high molecular weight BCP with domains large enough to interact with visible light. A large poly(styrene-b-2-vinylpyridine) (PS-b-P2VP, 793 K.g.mol$$^{-1}$$, PS:P2VP~1:24:1) BCP was used to obtain periodic hexagonal P2VP microdomains of 115 nm with spacing greater than 160 nm (Figure 3b). The pattern is thought to be a kinetically metastable phase. Infiltration of P2VP microdomains with iron ions and removal of the PS by UV-O3 resulted in an array of iron oxide dots, used as a mask for etching. Considering the large molecular weight of the BCP, achieving microphase separation is promising for applications requiring AR in the visible spectrum. Indeed, the large size and spacing of P2VP microdomains, as well as the high etch contrast of the iron oxide mask enabled fabrication of large and high aspect ratio nanopillars on various substrates. Omnidirectional and broadband reduction of reflectivity of silicon at two orders of magnitude (reflectivity below 0.16%) was achieved. Furthermore, the reflection remained low (around 1.7%) at higher angle of incident, up to 75° in the visible light range. This is attributed to the height of nanopillars (600-1100 nm).

**Discussion, Challenges and Opportunities**

For an efficient broadband and omnidirectional AR effect in the visible range (400-700 nm), surfaces need to be patterned with high aspect ratio nanopillars and a periodicity larger than 100 nm (typically $\frac{1}{2}$ $\lambda$, of the smallest wavelength of incident light). Achieving such dimensions using a BCP-derived mask requires use of large molecular weight BCPs. This is challenging for several reasons:

(a) Synthesizing high molecular weight BCPs above 500,000 kg/mol faces significant challenges for both the molecular mass monodispersity of the BCP and the reproducibility of synthesis. It typically requires minimizing the level of impurities in the synthesis reactor, at low temperature. The obtained polymers can be poorly soluble, limiting the homogeneity of the resulting BCP films.

(b) With a few exceptions, BCPs do not easily phase separate above 100 nm microdomains. This issue arises from significant kinetic penalties and larger chain entanglement in high molecular weight polymers.

(c) Obtaining high aspect ratio nanopillars (greater than 4) from large microdomains (100 nm or above) requires etching the substrate more than 400 nm deep. The current etch resistance and selectivity of masks obtained from BCP patterns, although sufficient for etching high aspect-ratio structures in silicon,41,43,64 need improvement for reaching similar capabilities on other substrates such as glass41,65 or sapphire. The amorphous nature of glass makes it more difficult to etch.

To overcome these challenges, new large BCPs may be designed with blocks presenting large Flory-Huggins parameters in order to facilitate their microphase separation.66 Combining lower molecular weight BCP with another component such as inorganic blocks or metals, leading to a hybrid system, offers an alternative solution for generating resistant and large mask features.47-49 With these BCPs available to form masks, reduced reflection for a range of substrates in the visible spectrum may be within reach. Should AR in the near infrared (NIR) spectrum be required, it will be critical to further advance this development, as patterns with high periodicity (above 100 nm) will be needed.

Beside the challenges associated with assembling large mask features, fabrication methods using BCPs have been limited in industrial use due to a tendency to find large defect densities in the resulting surface nanostructure, affecting the performance and consistency of the component in its intended device. Indeed, dewetting or poorly microphase-separated areas in BCP films will ultimately translate into lack of homogeneity for the pillar/nanostructure density after etching the substrate. Solving these issues requires a better control over...
environmental parameters that influence the microphase-separation. Specifically, the annealing conditions and the film processing methods could be optimized with a better understanding of the relationship between thermodynamic and kinetic pathways for BCP microphase-separation. Studying this relationship would require the development of more advanced equipment capable to observe the separation in-situ. While selectively infiltrating BCP blocks with metallic ions successfully forms a metal-oxide masks with good etch contrast (Figure 2b), the fundamental mechanism driving this process should be better understood, to avoid size polydispersity of the metal-oxide domains. Finally, some industrial requirements are still to be validated, such as to confirm the durability and robustness of the nanostructured AR surfaces and their environmental impact, in comparison to benchmark AR coatings.

Despite the challenges that remain before entering the market, there are many reasons to be optimistic for the future of nanostructured AR surfaces derived from microphase-separated BCPs. This approach has the potential to be the most viable manufacturing method for commercialisation, in terms of cost efficiency, scalability and adaptability to surfaces of large size and with complex shape. With further development, in addition to AR, this nanostructuring method could also be used to give other functionalities to surfaces, including self-cleaning, antifogging and structural colouring over large areas.

Acknowledgments
This project has received funding from the European Union’s Horizon 2020 research and innovation programme under the Marie Skłodowska-Curie grant agreement No. 715657, and from the European Union’s Horizon 2020 research and innovation programme under grant agreement No 760915. This work was also supported by Enterprise Ireland Commercialization Fund under project No. 206727 and by Science Foundation Ireland (SFI) under grant Number 134.226.130.145.

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